

## S-5701 B Series

125°C OPERATION, SUPER LOW CURRENT CONSUMPTION, LOW VOLTAGE OPERATION, OMNIPOLAR DETECTION TYPE TMR MAGNETIC SENSOR IC

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Rev.1.0\_00

This IC, developed by TMR (tunnel magneto resistance effect) technology and CMOS technology, is a magnetic sensor IC that operates with super low current consumption and low voltage.

The output voltage level changes when this IC detects the intensity level of magnetic flux density. Using this IC with a magnet makes it possible to detect the open / close in various devices.

ABLIC Inc. offers a "magnetic simulation service" that provides the ideal combination of magnets and our magnetic sensor IC for customer systems. Our magnetic simulation service will reduce prototype production, development period and development costs. In addition, it will contribute to optimization of parts to realize high cost performance. For more information regarding our magnetic simulation service, contact our sales representatives.

### Features

- Super low current consumption (IDD = 160 nA typ.) contributes to device power saving and extended period operation of battery devices
- High sensitivity magnetic characteristics enable downsizing of magnets
- Contributes to accurate mechanism operation over a wide temperature range due to excellent thermal stability of magnetic characteristics (Refer to "2. Magnetic characteristics" in "■ Characteristics (Typical Data)" for details)
- Uses a thin (t0.80 mm max.) TSOT-23-3S package, contributing to the enhancement of the designs of devices

### Specifications

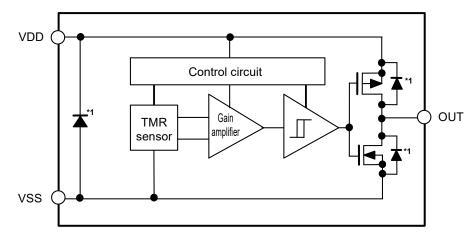
- Detection direction:
- Pole detection:
- Output logic:
- Output form:
- Magnetic sensitivity\*1:
- Operating cycle (current consumption):
- Power supply voltage range:
- Operation temperature range:
- Lead-free (Sn 100%), halogen-free
  - **\*1.** The option can be selected.

Horizontal direction (Refer to "**Depration**" for details) Omnipolar detection Active "L" CMOS output  $B_{OP} = 1.0 \text{ mT typ.}$   $B_{OP} = 3.0 \text{ mT typ.}$   $t_{CYCLE} = 100 \text{ ms (IDD} = 160 \text{ nA) typ.}$   $V_{DD} = 1.7 \text{ V to 5.5 V}$  $Ta = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ 

#### Applications

- Home security device
- (Window/door open/close detection) • Utility meter
- Battery powered device
- Wearable device
- Package
- TSOT-23-3S

### Block Diagram

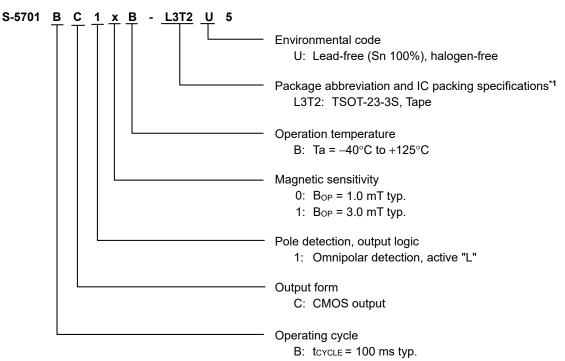


\*1. Parasitic diode

Figure 1

#### Product Name Structure

1. Product name



**\*1.** Refer to the tape drawing.

#### 2. Package

Table 1	Package	Drawing	Codes
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Package Name	Dimension	Таре	Reel
TSOT-23-3S	MP003-E-P-SD	MP003-E-C-SD	MP003-E-R-SD

#### 3. Product name list

Table 2

Product Name	Operating Cycle (tcycle)	Output Form	Pole Detection	Output Logic	Magnetic Sensitivity (Bop)
S-5701BC10B-L3T2U5	100 ms typ.	CMOS output	Omnipolar	Active "L"	1.0 mT typ.
S-5701BC11B-L3T2U5	100 ms typ.	CMOS output	Omnipolar	Active "L"	3.0 mT typ.

**Remark** Please contact our sales representatives for products other than the above.

## ■ Pin Configuraion

### 1. TSOT-23-3S

Top view



	Table	3
Pin No.	Symbol	Description
1	VSS	GND pin
2	VDD	Power supply pin
3	OUT	Output pin

Figure 2

### Absolute Maximum Ratings

#### Table 4 Unit Item Symbol Absolute Maximum Rating Power supply voltage Vdd $V_{\text{SS}}-0.3$ to $V_{\text{SS}}+6.0$ V Output current ±20 mΑ lout $V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$ V Output voltage Vout Maximum applied magnetic flux density mΤ Вмах ±50 °C Junction temperature T<sub>stg</sub> -40 to +150 Operation ambient temperature °C $\mathsf{T}_{\mathsf{opr}}$ -40 to +125 Storage temperature T<sub>stg</sub> -40 to +150 °C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Table 5

### ■ Thermal Resistance Value

Item	Symbol	Condition		Min.	Тур.	Max.	Unit
Junction-to-ambient thermal resistance*1	ALθ		Board A	-	225	-	°C/W
			Board B		190	-	°C/W
		TSOT-23-3S	Board C	-	_	-	°C/W
			Board D	-	_	-	°C/W
			Board E	_	_	-	°C/W

\*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

**Remark** Refer to "■ **Power Dissipation**" and "**Test Board**" for details.

### Electrical Characteristics

		(Ta = +25°C,	V <sub>DD</sub> = 3.3 V	Vss = 0 V	unless othe	erwise sp	pecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	Vdd	-	1.7	3.3	5.5	V	-
Current consumption		Average value, V <sub>DD</sub> = 3.3 V	-	160	320	nA	1
Current consumption	IDD	Average value, V <sub>DD</sub> = 5.5 V	_	500	720	nA	1
Low level output voltage	Vol	Ι <sub>Ουτ</sub> = 2 mA	-	-	$V_{\text{DD}} \times 0.1$	V	2
High level output voltage	Vон	$I_{OUT} = -2 \text{ mA}$	$V_{\text{DD}} \times 0.9$	1	_	V	3
Awake mode time	taw	—	-	2.1	-	μs	_
Sleep mode time	ts∟	—	-	100	-	ms	-
Operating cycle	<b>t</b> CYCLE	$t_{AW} + t_{SL}$	-	100	_	ms	—

Table 6

### Magnetic Characteristics

#### 1. Product with $B_{OP} = 1.0 \text{ mT typ.}$

#### Table 7

			(Ta = +25	°C, V <sub>DD</sub> = 3	3.3 V, V <sub>SS</sub> :	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOPS	-	0.4	1.0	1.5	mT	4
Operation point*1	N pole	BOPN	-	-1.5	-1.0	-0.4	mT	4
Release point*2	S pole	BRPS	-	0.1	0.5	0.9	mT	4
Release point -	N pole	BRPN	-	-0.9	-0.5	-0.1	mT	4
Uvotorogio width*3	S pole	BHYSS	BHYSS = BOPS – BRPS	_	0.5	-	mT	4
Hysteresis width*3	N pole	BHYSN	BHYSN =  BOPN - BRPN	—	0.5	-	mT	4

#### 2. Product with $B_{OP} = 3.0 \text{ mT typ.}$

#### Table 8

0500 14

			(Ia = +25	$^{\circ}C, V_{DD} = 3$	3.3 V, Vss	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation rejet*1	S pole	BOPS	_	2.0	3.0	4.0	mT	4
Operation point*1 N pole	N pole	BOPN	-	-4.0	-3.0	-2.0	mT	4
Deleges reint*2	S pole	BRPS	-	1.0	2.0	3.0	mT	4
Release point*2	N pole	B <sub>RPN</sub>	-	-3.0	-2.0	-1.0	mT	4
Hysteresis width <sup>*3</sup>	S pole	BHYSS	BHYSS = BOPS – BRPS	-	1.0	-	mT	4
	N nole	BUYEN	BHYSN = IBODN - BRDNI		10	_	mT	4

\*1. BOPN, BOPS: Operation points

 $B_{OPN}$  and  $B_{OPS}$  are the values of magnetic flux density when the output voltage (V<sub>OUT</sub>) changes after the magnetic flux density applied to this IC by the magnet (N pole or S pole) is increased (by moving the magnet closer). Even when the magnetic flux density exceeds  $B_{OPN}$  or  $B_{OPS}$ ,  $V_{OUT}$  retains the status.

\*2. BRPN, BRPS: Release points

 $B_{RPN}$  and  $B_{RPS}$  are the values of magnetic flux density when the output voltage (V<sub>OUT</sub>) changes after the magnetic flux density applied to this IC by the magnet (N pole or S pole) is decreased (the magnet is moved further away). Even when the magnetic flux density falls below  $B_{RPN}$  or  $B_{RPS}$ ,  $V_{OUT}$  retains the status.

\*3. B<sub>HYSN</sub>, B<sub>HYSS</sub>: Hysteresis widths B<sub>HYSN</sub> and B<sub>HYSS</sub> are the difference between B<sub>OPN</sub> and B<sub>RPN</sub>, and B<sub>OPS</sub> and B<sub>RPS</sub>, respectively.

**Remark** The unit of magnetic density mT can be converted by using the formula 1 mT = 10 Gauss.

### Test Circuits

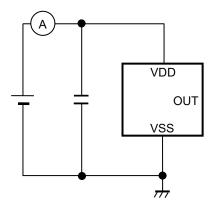


Figure 3 Test Circuit 1

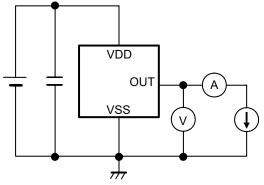
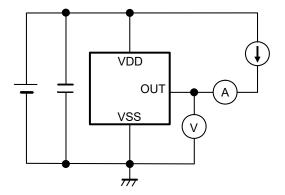


Figure 5 Test Circuit 3





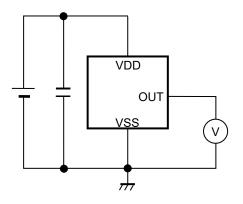
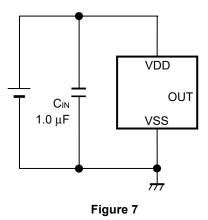


Figure 6 Test Circuit 4

### Standard Circuit



Caution The above connection diagram and constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constants.

### Operation

#### 1. Direction of applied magnetic flux

This IC detects the magnetic flux density which is horizontal to the package marking surface. A magnetic field is defined as positive when No.3 pin side of the package is the S pole, and negative when it is the N pole. **Figure 8** shows polarity in a magnetic field and direction in which magnetic flux is being applied.

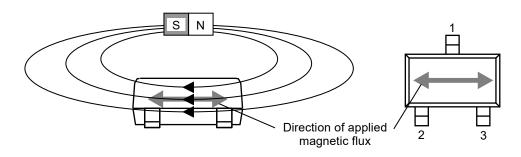


Figure 8

#### 2. Position of magnetic sensor

Figure 9 shows the position of a magnetic sensor.

The center of this magnetic sensor is located in the area indicated by a circle, which is in the center of a package as described below.

The following also shows the distance (typ. value) between the marking surface and the chip surface of a package.

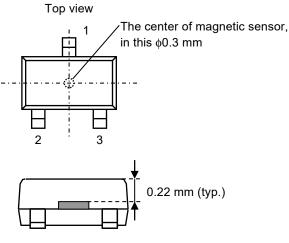


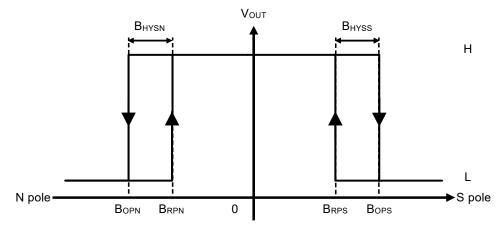
Figure 9

#### 3. Basic operation

This IC changes the output voltage ( $V_{OUT}$ ) according to the level of the magnetic flux density (N pole or S pole) applied by a magnet.

When the detected magnetic flux density exceeds the operation point ( $B_{OPN}$  or  $B_{OPS}$ ),  $V_{OUT}$  changes from "H" to "L". When the detected magnetic flux density becomes lower than the release point ( $B_{RPN}$  or  $B_{RPS}$ ),  $V_{OUT}$  changes from "L" to "H".

Figure 10 shows the relationship between the magnetic flux density and  $V_{OUT}$ .



Magnetic flux density (B)



#### 4. Time dependency in the current consumption

This IC performs the intermittent operation, and operates at low current consumption due to repeating the sleep mode and the awake mode.

Figure 11 shows the time dependency in the current consumption.

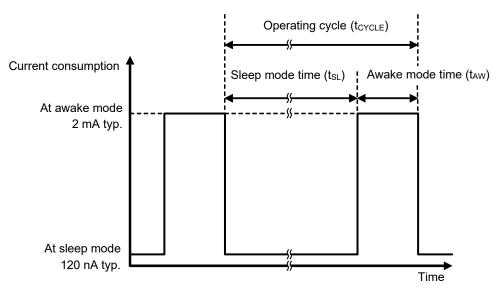


Figure 11

#### 5. Timing chart

Figure 12 shows the operation timing of this IC.

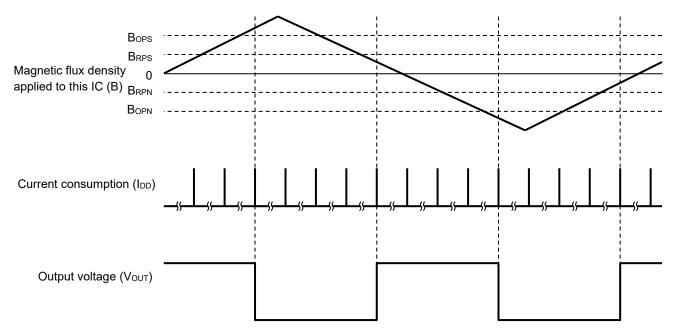


Figure 12

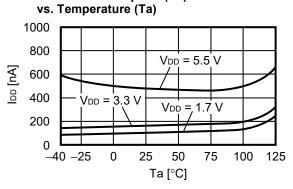
#### Precautions

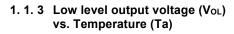
- If the impedance of the power supply is high, the IC may malfunction due to a supply voltage drop caused by feed-through current. Take care with the pattern wiring to ensure that the impedance of the power supply is low.
- Note that the IC may malfunction if the power supply voltage rapidly changes. When the IC is used under the
  environment where the power supply voltage rapidly changes, it is recommended to judge the output voltage of
  the IC by reading it multiple times.
- Note that the IC may take longer to change the output voltage according to the level of the magnetic flux density when power is supplied again just after power shutdown.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- Note that the output voltage may rarely change if the magnetic flux density between the operation point and the release point is applied to this IC continuously for a long time.
- The application conditions for the power supply voltage should not exceed the power dissipation.
- Large stress on this IC may affect the magnetic characteristics. Avoid large stress which is caused by the handling during or after mounting the IC on a board.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

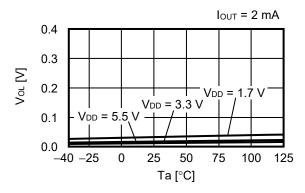
### ■ Characteristics (Typical Data)

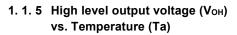
#### 1. Electrical characteristics

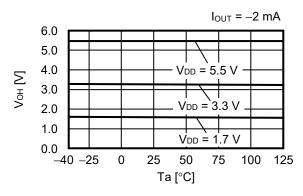
- 1.1 S-5701BC1xB
- 1. 1. 1 Current consumption (IDD)



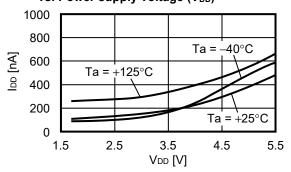




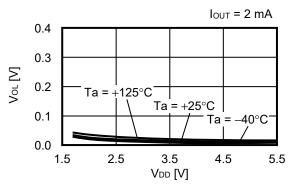


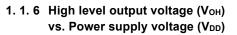


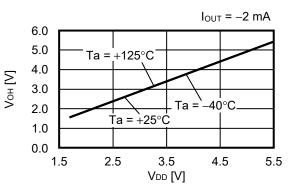
#### 1. 1. 2 Current consumption (I<sub>DD</sub>) vs. Power supply voltage (V<sub>DD</sub>)

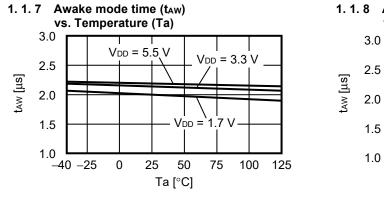


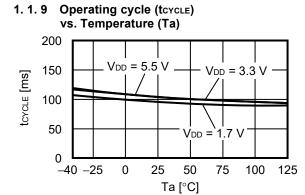
1. 1. 4 Low level output voltage (V<sub>DL</sub>) vs. Power supply voltage (V<sub>DD</sub>)



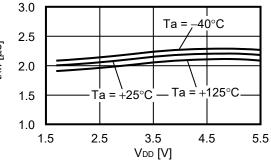


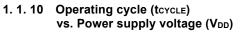


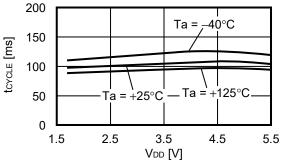




1. 1. 8 Awake mode time (t<sub>AW</sub>) vs. Power supply voltage (V<sub>DD</sub>)



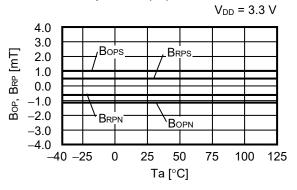




#### 2. Magnetic characteristics

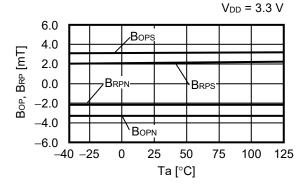
#### 2.1 S-5701BC10B

2. 1. 1 Operation point, release point (B<sub>OP</sub>, B<sub>RP</sub>) vs. Temperature (Ta)

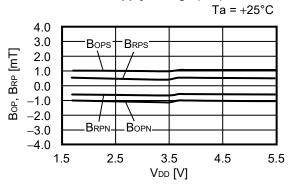


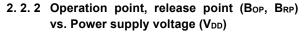
#### 2.2 S-5701BC11B

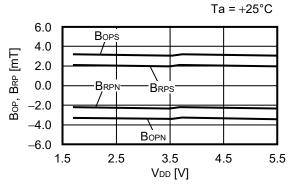
2. 2. 1 Operation point, release point (Bop, BRP) vs. Temperature (Ta)



2. 1. 2 Operation point, release point (B<sub>OP</sub>, B<sub>RP</sub>) vs. Power supply voltage (V<sub>DD</sub>)

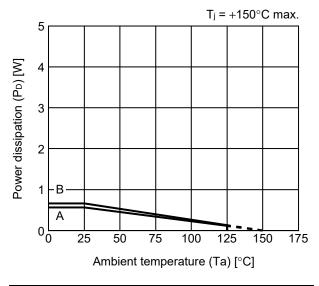






### Power Dissipation

### **TSOT-23-3S**



Board	Power Dissipation (P <sub>D</sub> )
А	0.56 W
В	0.66 W
С	_
D	_
E	_

# TSOT-23-3S Test Board

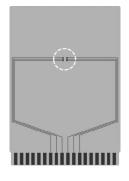
IC Mount Area

### (1) Board A



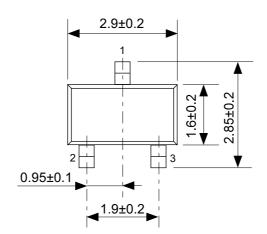
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		2
	1	Land pattern and wiring for testing: t0.070
Copper foil layer [mm]	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

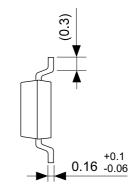
### (2) Board B

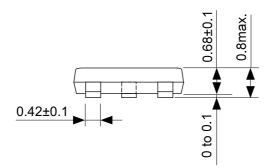


Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
	1	Land pattern and wiring for testing: t0.070
Connor foil lover [mm]	2	74.2 x 74.2 x t0.035
Copper foil layer [mm]	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. TSOT23x-A-Board-SD-1.0

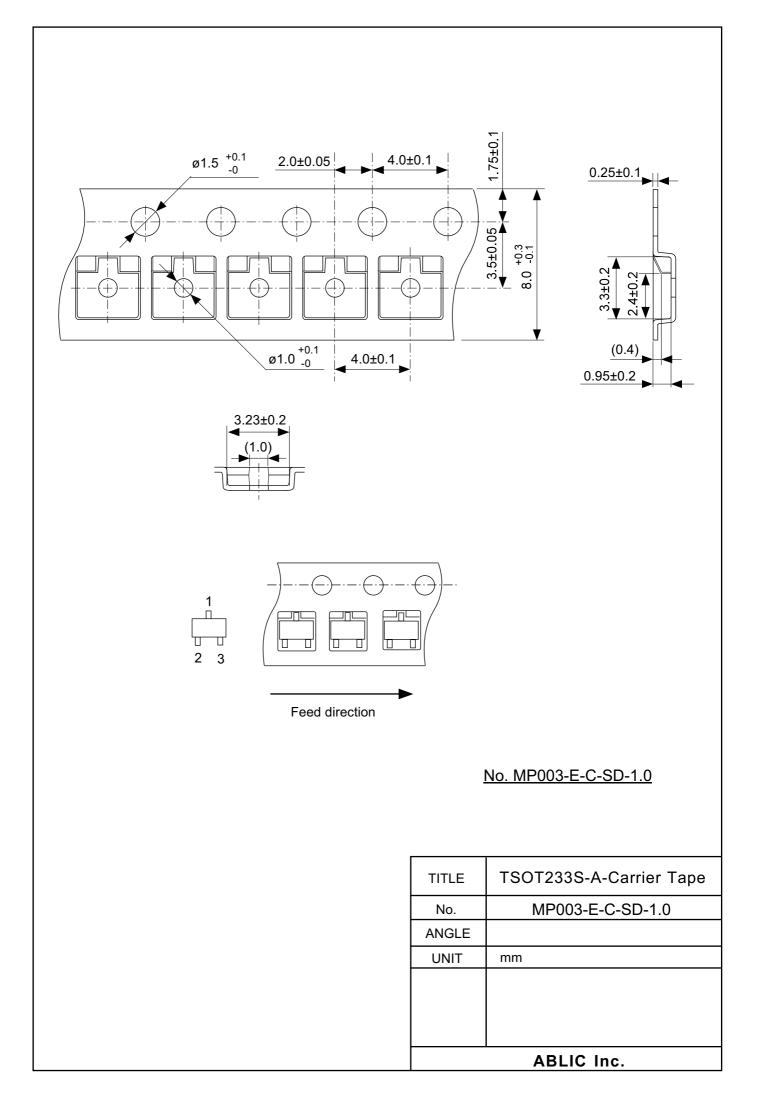


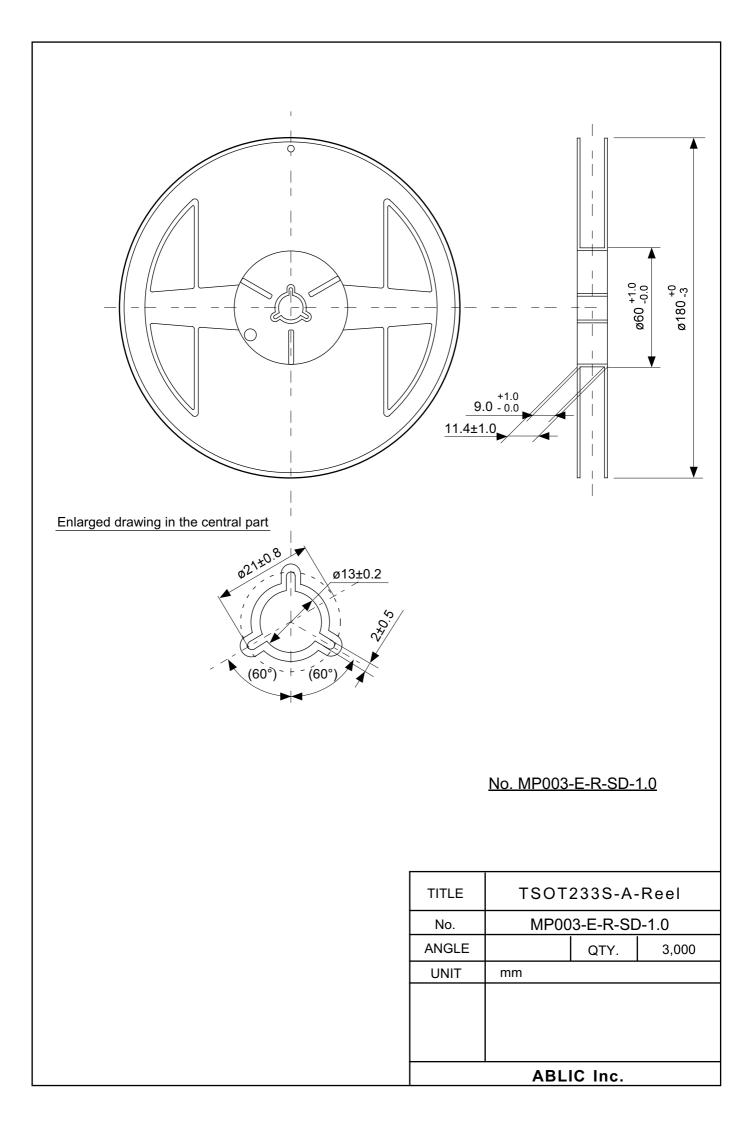




No. MP003-E-P-SD-1.0

TITLE	TSOT233S-A-PKG Dimensions		
No.	MP003-E-P-SD-1.0		
ANGLE	$\Phi$		
UNIT	mm		
ABLIC Inc.			





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2.4-2019.07